

Cell Library Databook

by Team S5

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December 9, 2013

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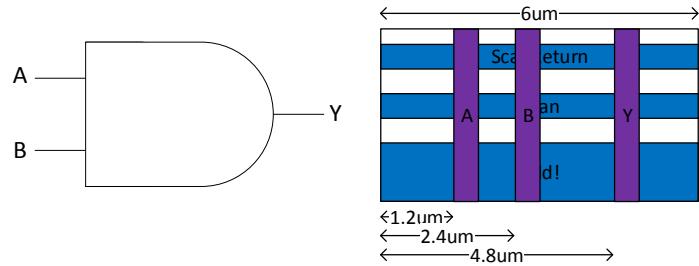
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1 And2

Designer: Constantijn Schepens

Cell Description: A two input AND gate

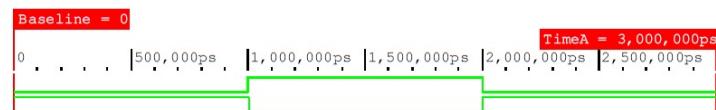
Symbol **Dimensions**



AC Characteristics

Signal	Delay (ps)
a propagation	121.7
b propagation	124.0

System Verilog Simulation

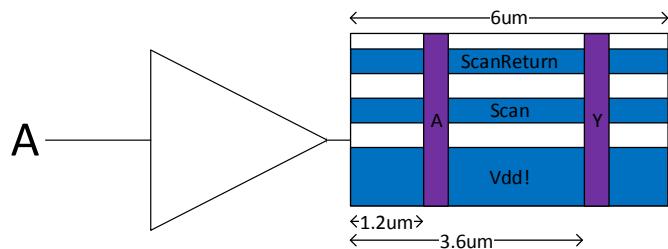


2 buffer

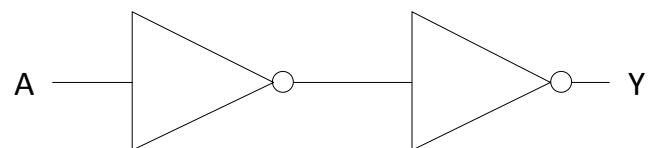
Designer: Ashley Robinson

Cell Description: A non-inverting buffer

Symbol Dimensions



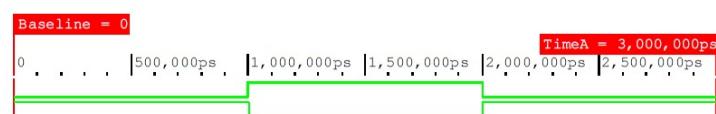
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
prop delay rise	138.5
prop delay fall	129.9
average prop	134.2

System Verilog Simulation

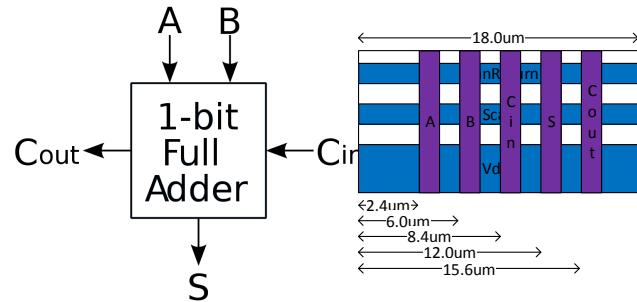


3 fulladder

Designer: Martin Wearn

Cell Description: Adds two bit values and the previous bits crie carry out, to produce a sum and carry

Symbol Dimensions



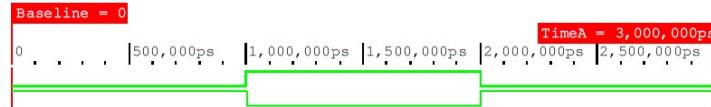
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
average a to s prop delay	294.9
average a to cout prop delay	285.0
average b to s prop delay	262.3
average b to cout prop delay	294.0
average cin to s prop delay	252.7
average cin to cout prop delay	274.6

System Verilog Simulation

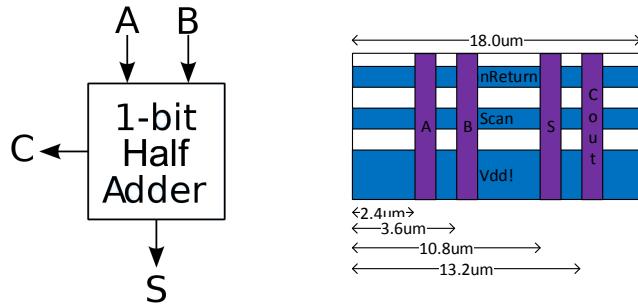


4 halfadder

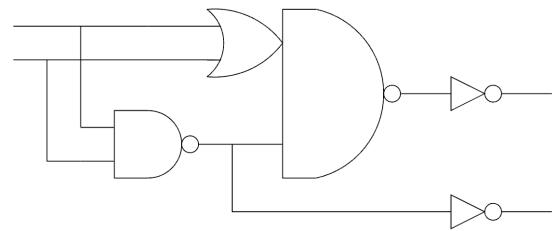
Designer: Martin Wearn

Cell Description: Adds two bits to produce a sum and carry

Symbol Dimensions



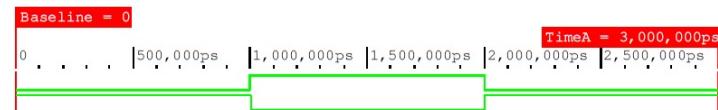
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
average a to s prop	251.7
average a to c prop	167.0
average b to s prop	240.9
average b to c prop	166.1

System Verilog Simulation

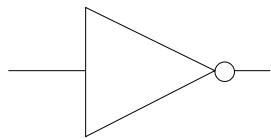


5 Inverter

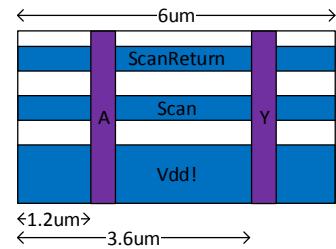
Designer: Henry Lovett

Cell Description: A basic inverter gate

Symbol



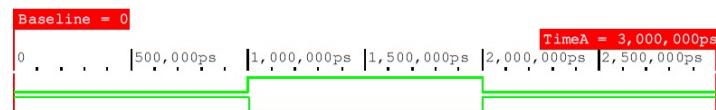
Dimensions



AC Characteristics

Signal	Delay (ps)
a rise delay	107.3
a fall delay	81.7

System Verilog Simulation

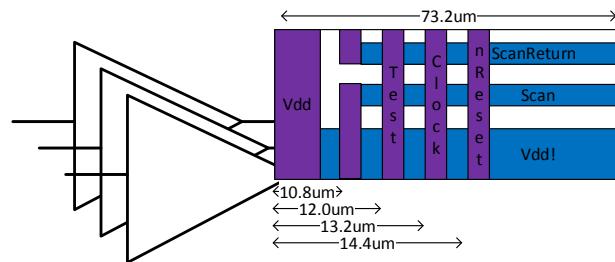


6 leftbuf

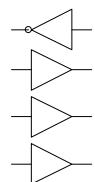
Designer: Henry Lovett

Cell Description: A start of row buffer cell.

Symbol Dimensions



Circuit Diagram



AC Characteristics

Signal	Delay (ps)
clock rise prop delay	287.5
clock fall prop delay	271.3
test rise prop delay	282.5
test fall prop delay	272.6
nreset rise prop delay	290.5
nreset fall prop delay	273.2
sdo rise prop delay	124.7
sdo fall prop delay	157.7

System Verilog Simulation

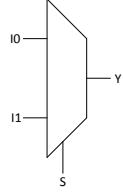


7 mux2

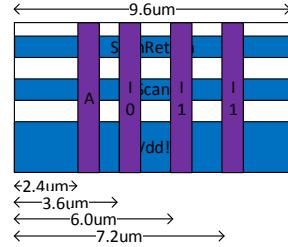
Designer: Constantijn Schepens

Cell Description: A two input Multiplexor

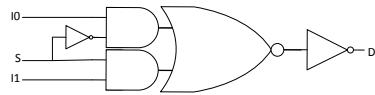
Symbol



Dimensions



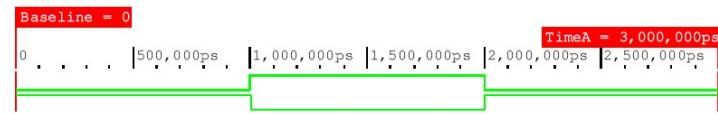
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
i0 propagation	182.5
i1 propagation	213.0
s pass i0 propagation	214.0
s pass i1 propagation	224.7

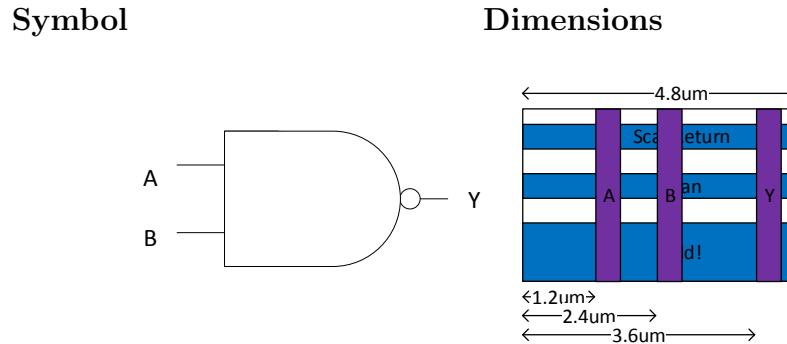
System Verilog Simulation



8 nand2

Designer: Constantijn Schepens

Cell Description: A two input NAND gate



AC Characteristics

Signal	Delay (ps)
a propagation	117.0
b propagation	117.6

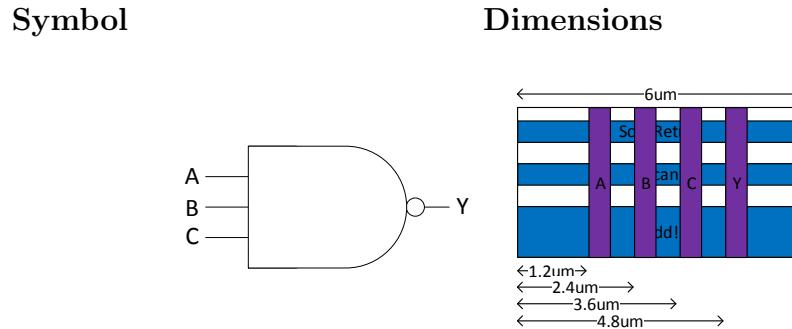
System Verilog Simulation



9 nand3

Designer: Constantijn Schepens

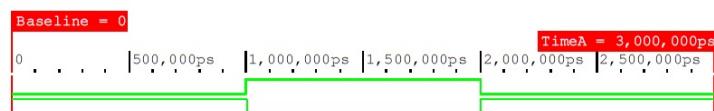
Cell Description: A three input NAND gate



AC Characteristics

Signal	Delay (ps)
a propagation	142.8
b propagation	142.3
c propagation	137.5

System Verilog Simulation

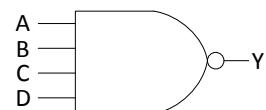


10 nand4

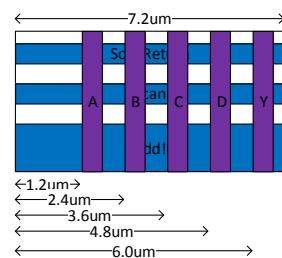
Designer: Constantijn Schepens

Cell Description: A four input NAND gate

Symbol



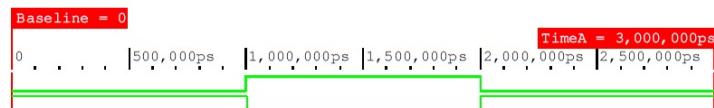
Dimensions



AC Characteristics

Signal	Delay (ps)
a propagation	171.0
b propagation	167.9
c propagation	165.1
d propagation	159.6

System Verilog Simulation

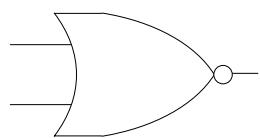


11 nor2

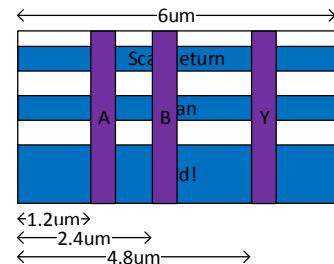
Designer: Henry Lovett

Cell Description: A two input NOR gate

Symbol



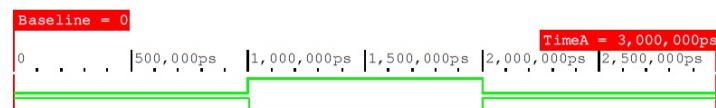
Dimensions



AC Characteristics

Signal	Delay (ps)
a rise prop delay	91.8
a fall prop delay	196.4
b rise prop delay	87.6
b fall prop delay	192.9

System Verilog Simulation

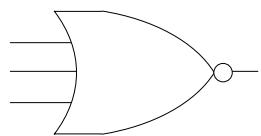


12 nor3

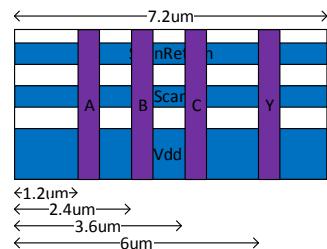
Designer: Henry Lovett

Cell Description: A three input NOR gate

Symbol



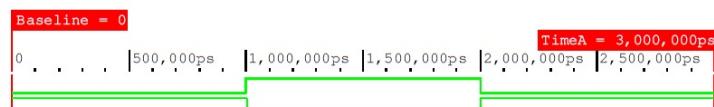
Dimensions



AC Characteristics

Signal	Delay (ps)
a rise prop delay	100.4
a fall prop delay	305.7
b rise prop delay	89.8
b fall prop delay	281.0
c rise prop delay	95.4
c fall prop delay	300.7

System Verilog Simulation

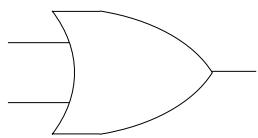


13 or2

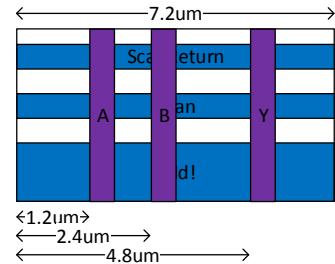
Designer: Henry Lovett

Cell Description: A two input OR gate

Symbol



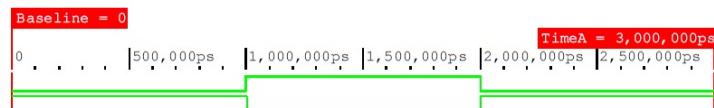
Dimensions



AC Characteristics

Signal	Delay (ps)
a fall delay	174.0
a rise delay	140.9
b fall delay	176.3
b rise delay	150.5

System Verilog Simulation

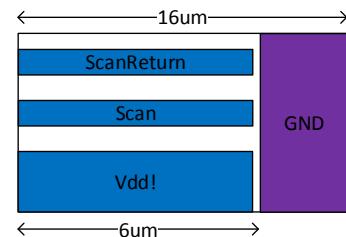
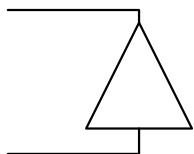


14 rightend

Designer: Henry Lovett

Cell Description: An end of row buffer cell.

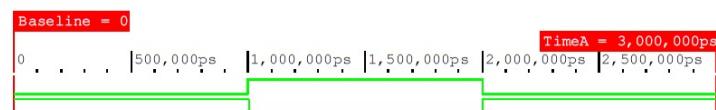
Symbol	Dimensions
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AC Characteristics

Signal	Delay (ps)
scan fall delay	56.4
scan rise delay	78.2

System Verilog Simulation

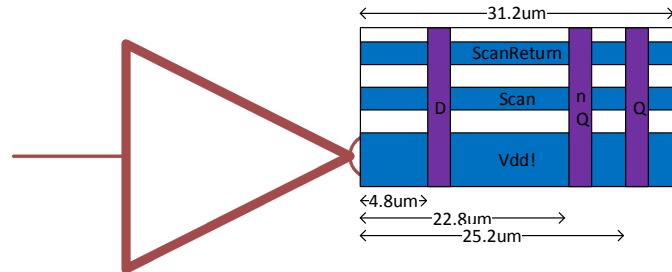


15 scandtype

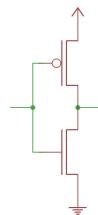
Designer: Constantijn Schepens

Cell Description: A scannable D-Type cell

Symbol **Dimensions**



Circuit Diagram



AC Characteristics

Signal	Delay (ps)
clock to q rise	336.9
clock to q fall	509.6
clock to nq rise	302.0
clock to nq fall	590.0
nreset to q fall	385.4
nreset to nq rise	177.7

System Verilog Simulation

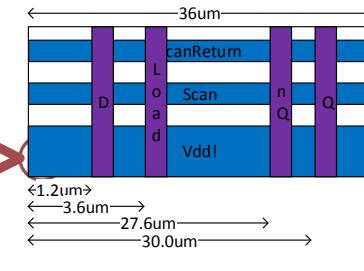


16 scanreg

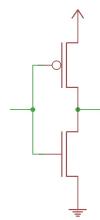
Designer: Constantijn Schepens

Cell Description: A scannable register cell

Symbol	Dimensions



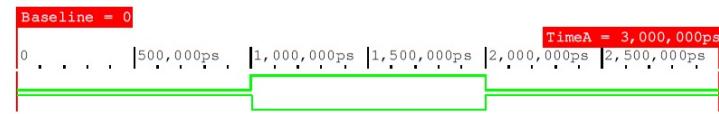
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
clock to q rise	357.2
clock to q fall	542.1
clock to nq rise	301.5
clock to nq fall	617.0
nreset to q fall	412.5
nreset to nq rise	178.3

System Verilog Simulation

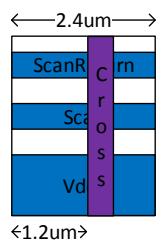


17 Rowcrosser

Designer: Martin Wearn

Cell Description: A row crossing cell.

Dimensions

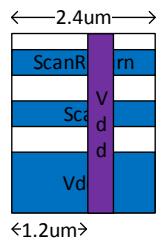


18 Tie High

Designer: Martin Wearn

Cell Description: A tie to Vdd cell.

Dimensions

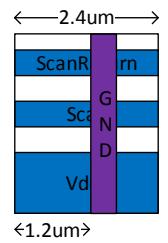


19 Tie Low

Designer: Martin Wearn

Cell Description: A tie low cell.

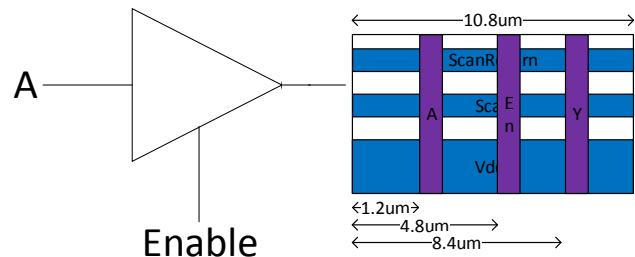
Dimensions



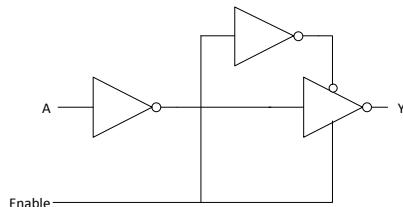
20 trisbuf

Designer: Ashley Robinson
Cell Description: A tristate buffer

Symbol **Dimensions**



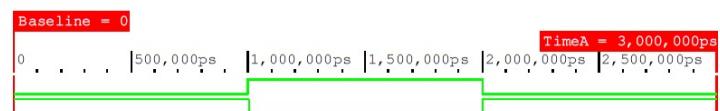
Circuit Diagram



AC Characteristics

Signal TO BE	Delay (ps) DONE
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System Verilog Simulation

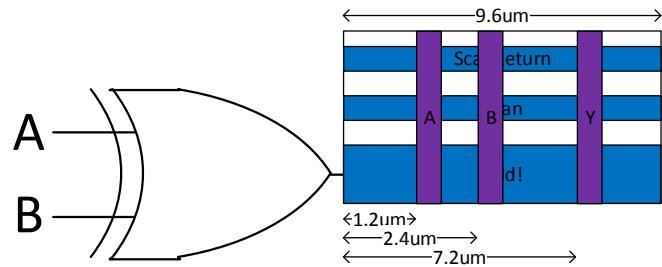


21 xor2

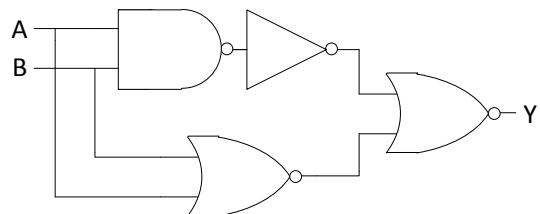
Designer: Ashley Robinson

Cell Description: A two input xor gate

Symbol Dimensions



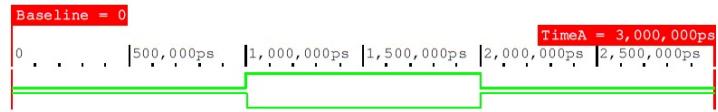
Circuit Diagram



AC Characteristics

Signal	Delay (ps)
prop delay a 1	305.0
prop delay a 2	241.7
prop delay b 1	184.3
prop delay b 2	201.7
average prop a	273.4
average prop b	193.0

System Verilog Simulation



A Appendix A

A.1 Team Management

A.2 Division of Labour

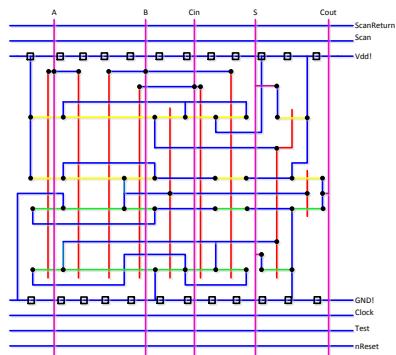
B Design Detail

B.1 fulladder

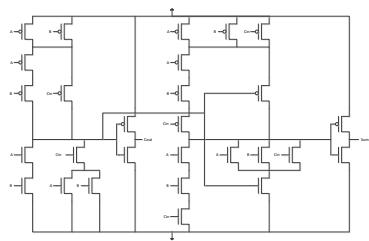
Designer: Martin Wearn

Cell Description: Adds two bit values and the previous bitslice carry out, to produce a sum and carry

Stick Diagram



Transistor Level Circuit Diagram

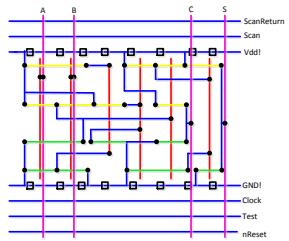


B.2 halfadder

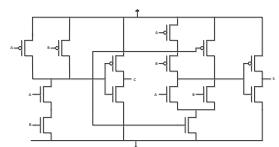
Designer: Martin Wearn

Cell Description: Adds two bits to produce a sum and carry

Stick Diagram



Transistor Level Circuit Diagram

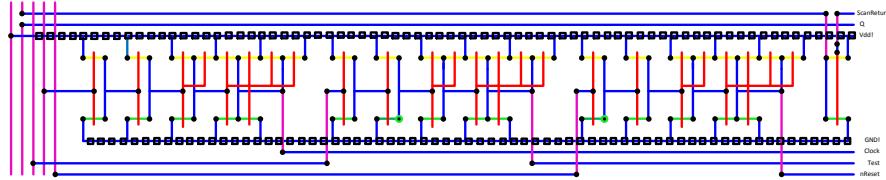


B.3 leftbuf

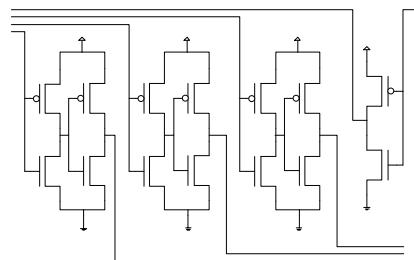
Designer: Henry Lovett

Cell Description: A start of row buffer cell.

Stick Diagram



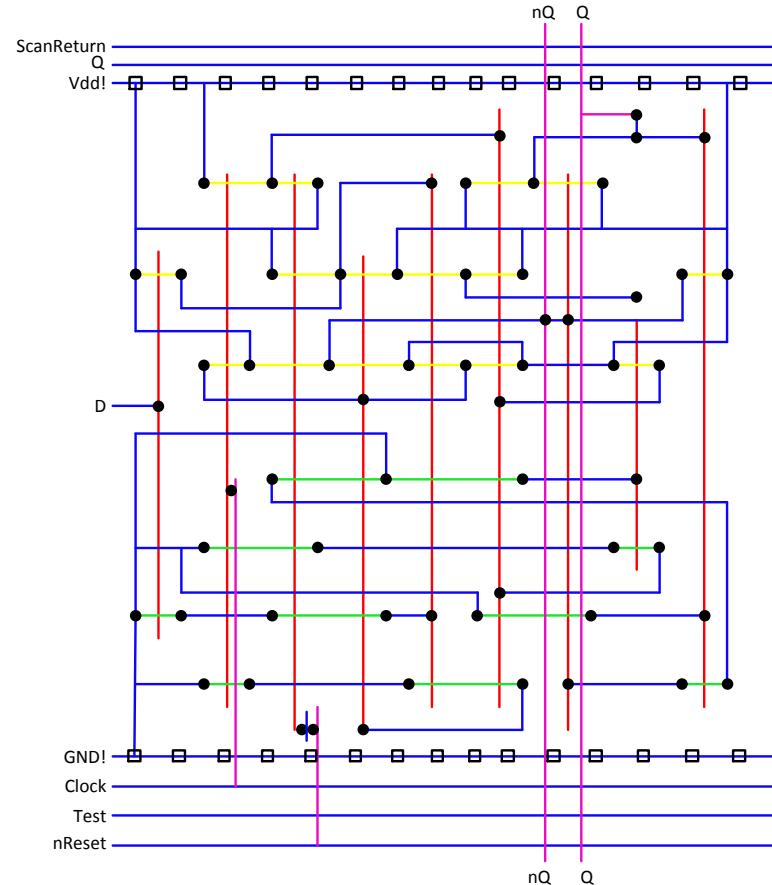
Transistor Level Circuit Diagram



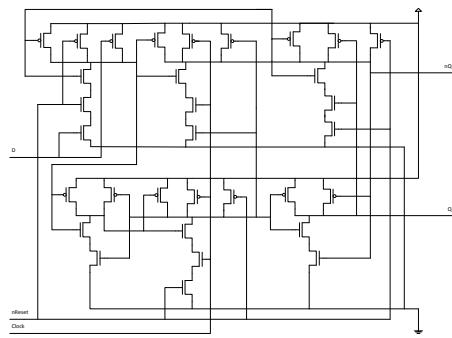
B.4 rdtype

Designer: Ashley Robinson
Cell Description: Raw Dtype

Stick Diagram



Transistor Level Circuit Diagram



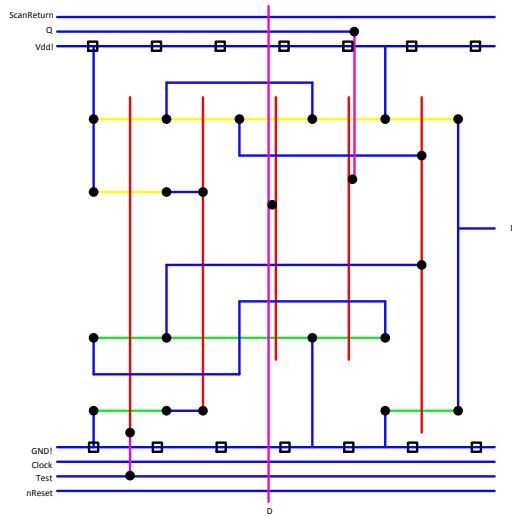
B.5 smux2

Designer: Constantijn Schepens

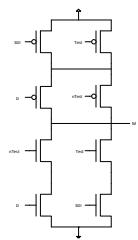
Cell Description: A 2 input scannable multiplexer, intended to be connected to a raw D-type to create a scannable D-type.

A single Euler path was used when laying out this cell, before taking into account inverters. The Euler path (T-nT-D-S) was designed such that the output was all the way on the right side such that it could connect directly to the D input of the raw D-type. Once this was done the required internal inverters were added in by creating a gate matrix design.

Stick Diagram



Transistor Level Circuit Diagram



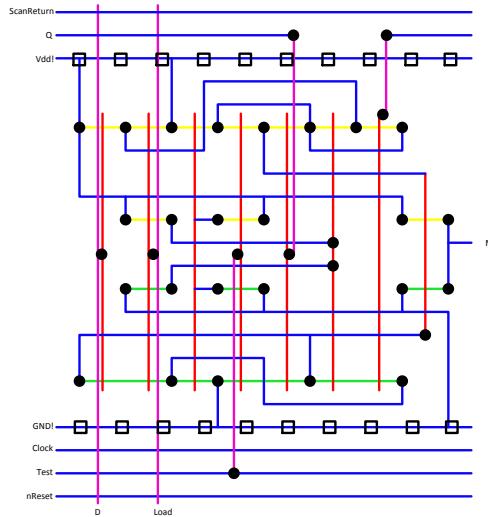
B.6 smux3

Designer: Constantijn Schepens

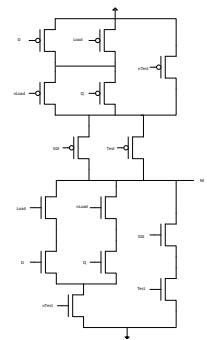
Cell Description: A 3 input scannable multiplexer, intended to be connected to a raw D-type to create a scannable register.

A similar approach was taken for the layout of this cell as for the smux2. Initially inverters were excluded and a single Euler path (D-Load-nTest-Test-SDI-nLoad-Q) was found that both kept M and Q as close to the right side as possible (to connect to the raw D-type) and kept the Test/Load nearest to their inverted partners for easy wiring. For the internal inverter placement multiple layouts were trialed to find the most efficient one, that also allowed all the internal wiring to be done with metal 1 exclusively(to reduce the number of vias).

Stick Diagram



Transistor Level Circuit Diagram

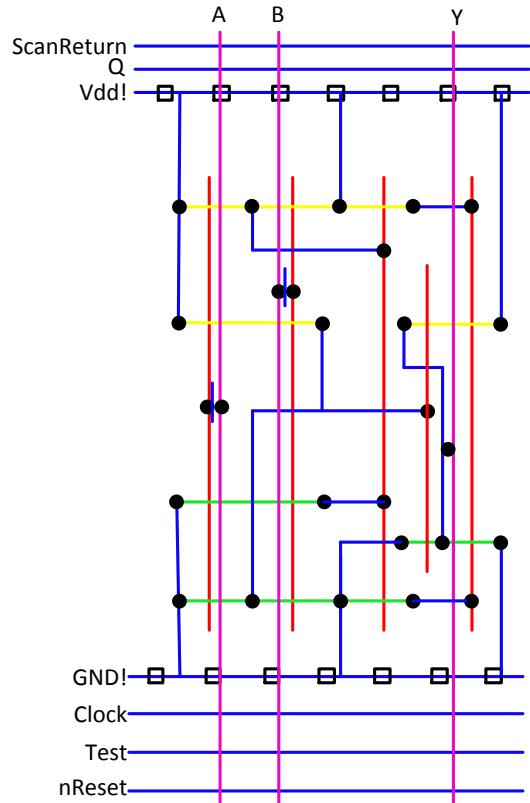


B.7 xor2

Designer: Ashley Robinson

Cell Description: A 2 input XOR gate.

Stick Diagram



Transistor Level Circuit Diagram

